# LM1MA141K LM1MA142K

This Silicon Epitaxial Planar Diode is designed for use in ultra high speed switching applications. This device is housed in the SOT–323 package which is designed for low power surface mount applications.

- Fast t<sub>rr</sub> < 3.0 ns</li>
- Low C<sub>rr</sub> < 2.0 pF
- We declare that the material of product compliance with RoHS requirements.
- Moisture Sensitivity Level 1

#### DEVICE MARKING AND ORDERING INFORMATION

Device	Package	Shipping
LM1MA141K	SOT-323	3000/Tape&Reel
LM1MA142K	SOT-323	3000/Tape&Reel

### Pb-Free package is available

RoHS product for packing code suffix "G"
Halogen free product for packing code suffix "H"

### **DEVICE MARKING**

LM1MA141K = MH $LM1MA142K = MI$
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### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating		Symbol	Value	Unit
Reverse Voltage	LM1MA141K	$V_R$	40	$V_{dc}$
	LM1MA142K		80	
Peak Reverse Voltage	LM1MA141K	$V_{RM}$	40	$V_{dc}$
	LM1MA142K		80	
Forward Current		$I_{F}$	100	mAdc
Peak Forward Current		$I_{FM}$	225	mAdc
Peak Forward Surge Current		I <sub>FSM</sub> <sup>(1)</sup>	500	mAdc

### THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation	$P_D$	150	mW
Junction Temperature	TJ	150	°C
Operating/Storage Temperature	$T_{\text{stg}}$	<b>−</b> 55 ~ +150	°C

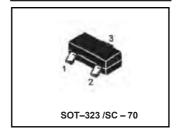
#### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

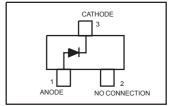
Characteristic		Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Curre	ent LM1MA141K	$I_R$	V <sub>R</sub> = 35 V	_	0.1	μAdc
	LM1MA142K		$V_{R} = 75 \text{ V}$	_	0.1	
Forward Voltage		$V_{F}$	$I_F = 100 \text{ mA}$	_	1.2	Vdc
Reverse Breakdown Voltage	LM1MA141K	$V_R$	$I_R$ = 100 $\mu$ A	40	_	Vdc
	LM1MA142K			80	_	
Diode Capacitance		C <sub>D</sub>	V <sub>R</sub> =0, f=1.0 MHz	_	2.0	pF
Reverse Recovery	Time	trr(2)	I <sub>F</sub> =10mA,V <sub>R</sub> =6.0V	_	3.0	ns
			$R_L=100\Omega$ , $I_{rr}=0.1$ $I_R$			

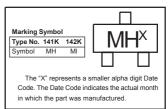
1. t = 1 SEC

2. t<sub>rr</sub> Test Circuit

SOT-323 PACKAGE SINGLE SILICON SWITCHING DIODE 40/80 V-100 mA SURFACE MOUNT



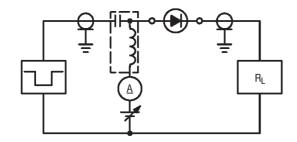






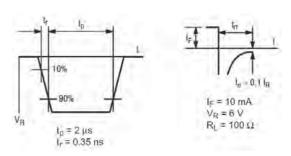
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### RECOVERY TIME EQUIVALENT TEST CIRCUIT



**INPUT PULSE** 

### **OUTPUT PULSE**



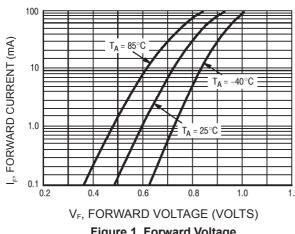
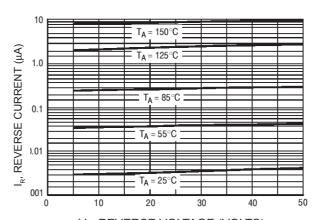
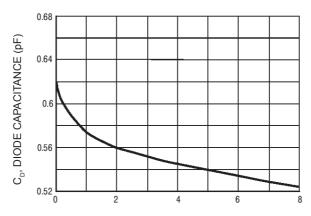


Figure 1. Forward Voltage



V<sub>R</sub>, REVERSE VOLTAGE (VOLTS)

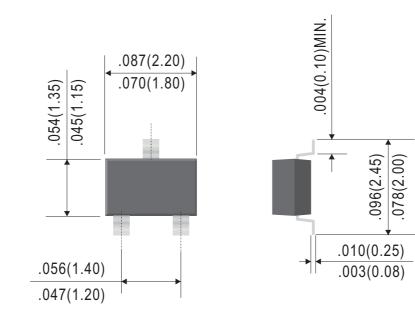
Figure 2. Reverse Current

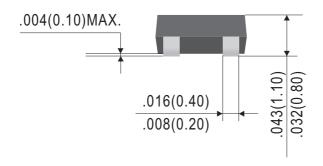


V<sub>R</sub>, REVERSE VOLTAGE (VOLTS)

Figure 3. Diode Capacitance

### SOT-323





Dimensions in inches and (millimeters)



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## **Ordering Information:**

Device PN	Packing
Part Number-T <sup>(1)</sup> G <sup>(2)</sup> -WS	Tape&Reel: 3 Kpcs/Reel

Note: (1) Packing code, Tape&Reel Packing

(2) RoHS product for packing code suffix "G"; Halogen free product for packing code suffix "H"

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